RENESAS

EL4332

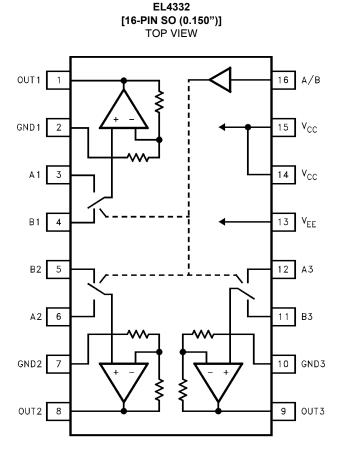
Triple 2:1 300MHz Mux-Amp AV = 2

The EL4332 is a triple very high speed 2:1 Multiplexer-Amplifier. It is intended primarily for component video multiplexing and is especially suited for pixel switching. The amplifiers have their gain set to 2 internally, which reduces the need for many external components. The gain-of-2 facilitates driving back terminated cables. All three amplifiers are switched simultaneously from their A to B inputs by the TTL/CMOS compatible, common A/B control pin.

A -3dB bandwidth of 300MHz together with 3ns multiplexing time enable the full performance of the fastest component video systems to be realized.

The EL4332 runs from standard $\pm 5V$ supplies, and is available in the narrow 16-pin small outline package.

Pinout



DATASHEET

FN7163 Rev 2.00 October 4, 2004

Features

- 3ns A-B switching
- 300MHz bandwidth
- Fixed gain of 2, for cable driving
- > 650V/µs slew rate
- TTL/CMOS compatible switch
- Pb-free available

Applications

- RGB multiplexing
- Picture-in-picture
- Cable driving
- HDTV processing
- Switched gain amplifiers
- ADC input multiplexer

Ordering Information

PART NUMBER	PACKAGE	TAPE & REEL	PKG. DWG. #
EL4332CS	16-Pin SO (0.150")	-	MDP0027
EL4332CS-T7	16-Pin SO (0.150")	7"	MDP0027
EL4332CS-T13	16-Pin SO (0.150")	13"	MDP0027
EL4332CSZ (Note)	16-Pin SO (0.150") (Pb-Free)	-	MDP0027
EL4332CSZ-T7 (Note)	16-Pin SO (0.150") (Pb-Free)	7"	MDP0027
EL4332CSZ-T13 (Note)	16-Pin SO (0.150") (Pb-Free)	13"	MDP0027

NOTE: Intersil Pb-free products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which is compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J Std-020B.

Demo Board

A demo PCB is available for this product.



Absolute Maximum Ratings $(T_A = 25^{\circ}C)$

V _{CC} to V _{EE}
V _{CC} to any GND12V
V _{EE} to any GND12V
Continuous Output Current 45mA
Any Input V _{EE} -0.3V to V _{CC} +0.3V

 Input Current, Any Input.
 5mA

 Power Dissipation
 See Curves

 Ambient Operating Temperature
 -40°C to 85°C

 Junction Temperature
 150°C

 Storage Temperature.
 -60°C to +150°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

PARAMETER	DESCRIPTION	MIN	ТҮР	MAX	UNITS
V _{OS}	Input Referred Offset Voltage		8	20	mV
dV _{OS}	Input Referred Offset Voltage Delta (Note 1)		2	8	mV
R _{IN}	Input Resistance		30		kΩ
IB	Input Bias Current		-7	-30	μA
dl _B	Input Bias Current Delta (Note 1)		0.5	4.0	μA
A _V	Gain	1.94	2.00	2.06	V/V
dA _V	Gain Delta (Note 1)		0.5	2.5	%
C _{IN}	Input Capacitance		3.3		pF
PSRR	Power Supply Rejection Ratio	50	70		dB
Vo	Output Voltage Swing into 500Ω load	±2.7	±3.6		V
	Output Voltage Swing into 150Ω load		+3/-2.7		V
Ιουτ	Current Output, Measured with 75Ω Load (Note 2)	30	40		mA
Xtalk _{AB}	Crosstalk from Non-selected Input (at DC)	-70	-100		dB
Xtalk _{CH-CH}	Crosstalk from one Amplifier to another Amplifier	-70	-100		dB
V _{IH}	Input Logic High Level	2.0			V
V _{IL}	Input Logic Low Level			0.8	V
IIL	Logic Low Input Current (VIN = 0V)	-0.3	-40	-80	μA
IIH	Logic High Input Current (V _{IN} = 0V)	-3	0	3	μA
I _S	Total Supply Current	38	48	60	mA

DC Electrical Specifications $V_{CC} = +5V$, $V_{EE} = -5V$, Temperature = 25°C, $R_L = \infty$

NOTES:

1. Each channel's A-input to its B-input.

2. There is no short circuit protection on any output.

AC Electrical Specifications	V_{CC} = +5V, V_{EE} = -5V, Temperature = 25°C, R_L = 150 Ω , C_L = 3pF.
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PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNITS
BW	-3dB Bandwidth		300		MHz
BW 0.1dB	±0.1dB Bandwidth		105		MHz
DG	Differential Gain at 3.58MHz		0.04		%
DP	Differential Phase at 3.58MHz		0.08		0
Pkg	Peaking with Nominal Load		0.2		dB
SR	Slew Rate (4V Square Wave, Measured 25%-75%)		650		V/µs



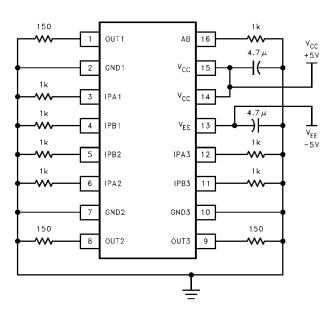
PARAM	IETER	DESCRIPTION	MIN	TYP	MAX	UNITS
ts		Settling Time to 0.1% of Final Value		13		ns
T _{SW}		Time to Switch Inputs		3		ns
OS	DS Overshoot, $V_{OUT} = 4V_{P-P}$ 8			%		
I _{SO} ab	10M	Input to Input Isolation at 10MHz		60		dB
	100M	Input to Input Isolation at 100MHz		40		dB
I _{SO} ch-ch	10M	Channel to Channel Isolation at 10MHz		61		dB
	100M	Channel to Channel Isolation at 100MHz		50		dB

AC Electrical Specifications $V_{CC} = +5V$, $V_{EE} = -5V$, Temperature = $25^{\circ}C$, $R_L = 150\Omega$, $C_L = 3pF$. (Continued)

Pin Descriptions

PIN NAME	FUNCTION		
A1, A2, A3	"A" inputs to amplifiers 1, 2 and 3 respectively.		
B1, B2, B3	"B" inputs to amplifiers 1, 2 and 3 respectively.		
GND1, GND2, GND3	These are the individual ground pins for each channel.		
Out1, Out2, Out3	Amplifier outputs. Note: there is no short circuit protection on any output.		
V _{CC}	Positive power supply. Typically +5V.		
V _{EE}	Negative power supply. Typically -5V.		
A/B	Common input select pin, a logic high selects the "A" inputs, logic low selects the "B" inputs. CMOS/TTL compatible.		

Burn In Schematic



Typical Performance Curves

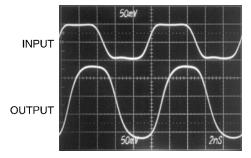


FIGURE 1. SMALL SIGNAL TRANSIENT RESPONSE

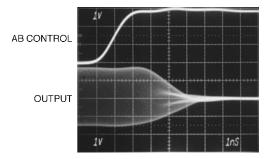


FIGURE 3. SWITCHING TO GROUND FROM A LARGE SIGNAL UNCORRELATED SINE WAVE

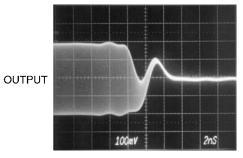


FIGURE 5. SWITCHING TO GROUND FROM A SMALL SIGNAL UNCORRELATED SINE WAVE

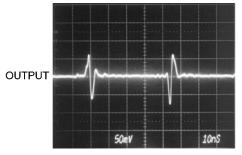


FIGURE 7. SWITCHING GLITCH (INPUTS AT GROUND)

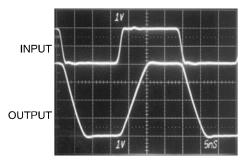


FIGURE 2. LARGE SIGNAL TRANSIENT RESPONSE

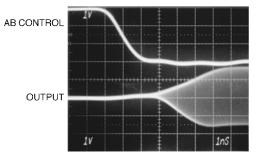


FIGURE 4. SWITCHING FROM GROUND TO A LARGE SIGNAL UNCORRELATED SINE WAVE

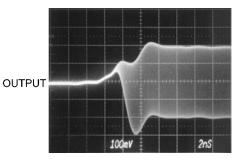


FIGURE 6. SWITCHING FROM GROUND TO A SMALL SIGNAL UNCORRELATED SINE WAVE

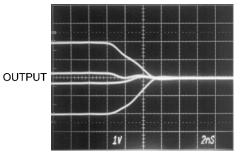
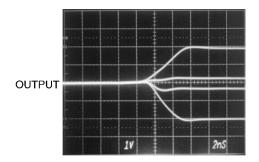


FIGURE 8. SWITCHING FROM A FAMILY OF DC LEVELS TO GROUND



Typical Performance Curves (Continued)





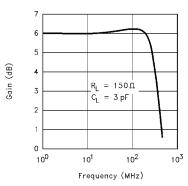


FIGURE 11. GAIN vs FREQUENCY

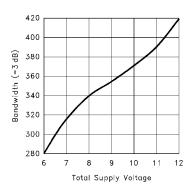


FIGURE 13. -3dB BW vs SUPPLY VOLTAGE

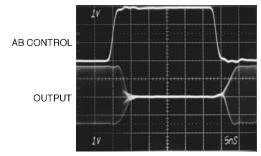


FIGURE 10. CHANNEL A/B SWITCHING DELAY

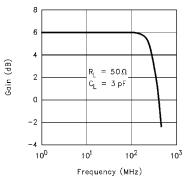


FIGURE 12. GAIN vs FREQUENCY

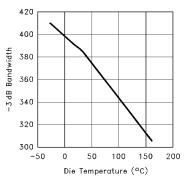
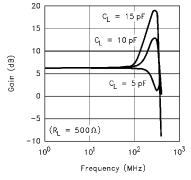


FIGURE 14. BANDWIDTH vs DIE TEMPERATURE



Typical Performance Curves (Continued)





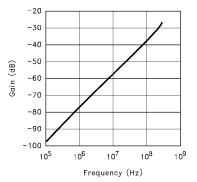


FIGURE 17. A-INPUT TO B-INPUT ISOLATION

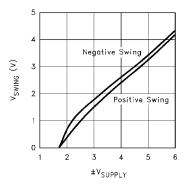


FIGURE 19. OUTPUT SWING vs SUPPLY VOLTAGE

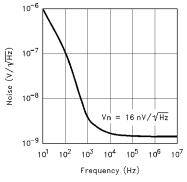


FIGURE 16. INPUT VOLTAGE NOISE OVER FREQUENCY

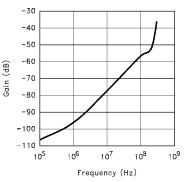


FIGURE 18. CHANNEL-CHANNEL ISOLATION

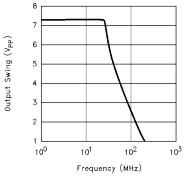


FIGURE 20. OUTPUT SWING vs FREQUENCY



Typical Performance Curves (Continued)

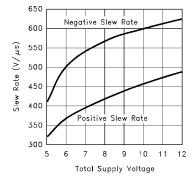


FIGURE 21. SLEW RATE vs SUPPLY VOLTAGE

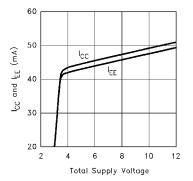


FIGURE 23. SUPPLY CURRENT vs SUPPLY VOLTAGE

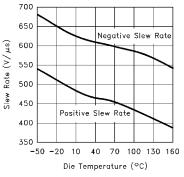
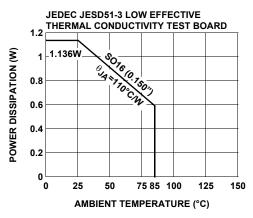
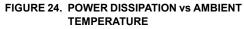


FIGURE 22. SLEW RATE vs DIE TEMPERATURE





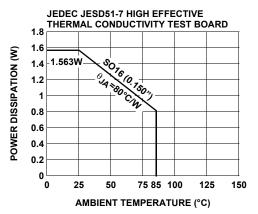


FIGURE 25. POWER DISSIPATION vs AMBIENT TEMPERATURE

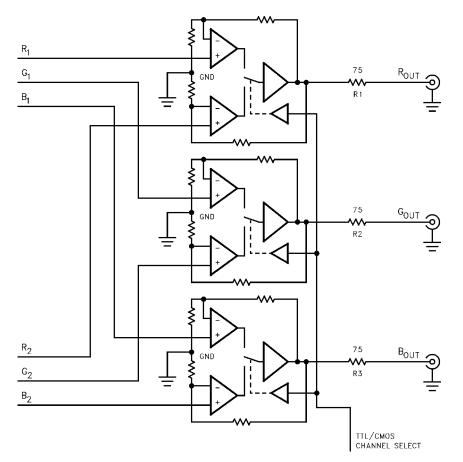


FIGURE 26. TYPICAL CONNECTION FOR A 2:1 COMPONENT VIDEO MULTIPLEXER

Applications Information

Figure 26 shows a typical use for the EL4332. The circuit is a component video (R,G, B or Y,U,V) multiplexer. Since the gain of the internal amplifiers has been set to 2, the only extra components needed are the supply decoupling capacitors and the back terminating resistors, if transmission lines are to be driven. The EL4332 can drive backmatched 50Ω or 75Ω loads.

Grounds

It will be noticed that each mux-amp channel has its own separate ground pin. These ground pins have been kept separate to keep the channel separation inside the chip as large as possible. The feedback resistors use these ground pins as their reference. The resistors total 400 Ω , so there is a significant signal current flowing from these pins to ground.

The ground pins should all be connected together, to a ground plane underneath the chip. 1 oz. copper for the ground plane is highly recommended.

Further notes and recommended practices for high speed printed circuit board layout can be found in the tutorials in the Elantec databooks.

Supplies

Supply bypassing should be as physically near the power pins as possible. Chip capacitors should be used to minimize lead inductance. Note that larger values of capacitor tend to have larger internal inductances. So when designing for 3 transmission lines or similar moderate loads, a 0.1μ F ceramic capacitor right next to the power pin in parallel with a 22μ F tantalum capacitor placed as close to the 0.1μ F is recommended. For lighter loadings, or if not all the channels are being used, a single 4.7μ F capacitor has been found quite adequate.

Note that component video signals do tend to have a high level of signal correlation. This is especially true if the video signal has been derived from 3 synchronously clocked DACs. This corresponds to all three channels drawing large slew currents simultaneously from the supplies. Thus, proper bypassing is critical.



Logic Inputs

The A/B select, logic input, is internally referenced to ground. It is set at 2 diode drops above ground, to give a threshold of about 1.4V (see Figure 27). The PNP input transistor requires that the driving gate be able to sink current, typically < 30μ A, for a logic "low". If left to float, it will be a logic "high".

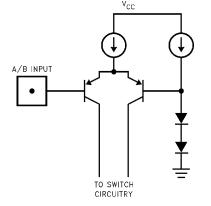
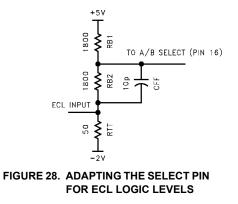


FIGURE 27. SIMPLIFIED LOGIC INPUT STAGE

The input PNP transistors have sufficient gain that a simple level shift circuit (see Figure 28) can be used to provide a simple interface with Emitter Coupled Logic. Typically, 200mV is enough to switch from a solid logic "low" to a "high."



The capacitor C_{FF} is only in the network to prevent the A/B pin's capacitance from slowing the control signal. The network shown level shifts the ECL levels, -0.7V to -1.5V to +1.6V and +1.1V respectively. The terminating resistor, R_{TT}, is required since the open emitter of the ECL gate can not sink current. If a -2V rail is not being used, a 220 Ω to 330 Ω resistor to the -5.2V rail would have the same effect.



Expanding the Multiplexer

In Figure 29, a 3:1 multiplexer circuit is shown. The expansion to more inputs is very straight forward. Since the EL4332 has a fixed gain of 2, interstage attenuators may be required as shown in Figure 28. The truth table for the 3:1 multiplexer select lines is:

TABLE 1.

х	Y	ΜUX OUTPUT
0	0	R3, G3, B3
0	1	R2, G2, B2
1	Х	R1, G1, B1

When interstage attenuators are used, the values should be kept down in the region of 50Ω -300 Ω . This is to prevent a combination of circuit board stray capacitance and the EL4332's input capacitance forming a significant pole. For example, if instead of 100 Ω as shown, resistors of 1k Ω had been used, and assuming 3pF of stray and 3pF of input capacitance, a pole would be formed at about 53MHz.

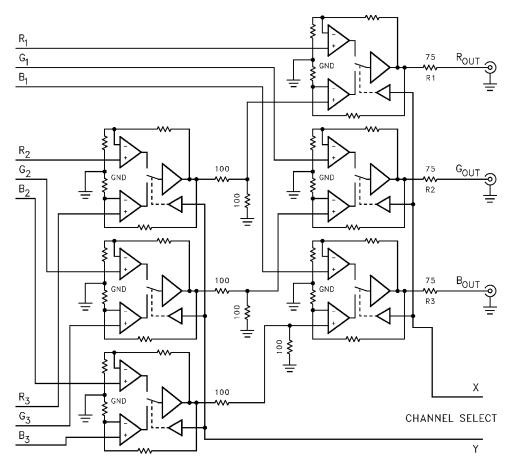


FIGURE 29. TYPICAL CONNECTION FOR A 3:1 COMPONENT VIDEO MULTIPLEXER

A Bandwidth Selectable Circuit

In Figure 30, a circuit is shown that allows three signals to be either low pass filtered or full bandwidth.

This could be useful where an input signal is frequently noisy. The component values shown give a Butterworth LPF response, with a -3dB frequency of 50MHz. Note again, the resistor values are low, so that stray capacitance does not affect the desired cut-off frequency.

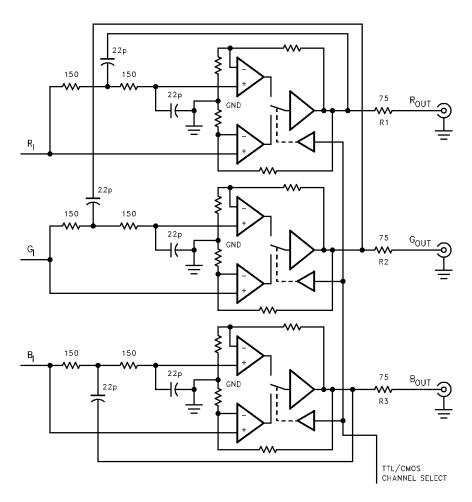


FIGURE 30. SWITCHED 50MHz LOW PASS FILTER FOR HIGH/LOW RESOLUTION MONITORS

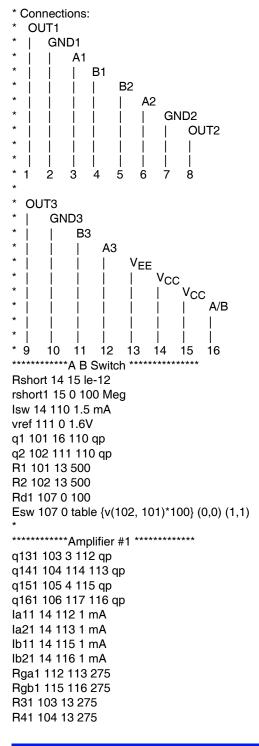


EL4332 Macromodel

* EL4332 Macromodel

* Revision A, April 1996

*Applications Hints. The EL4332 has two V_{CC} pins, one V_{EE} pin, and three ground *pins. The V_{CC} pins (pins 14 and 15 are internally shorted together in the model, *but the ground pins (GND1, GND2, and GND3 (nodes 2, 7, and 10, respectively) *must be connected to ground (node 0) using a le-6W resistor. Alternatively, * nodes 2, 7, and 10 may be connected to ground through a 25Ω resistor in parallel * with a 4nH inductor to simulate package and PCB parasitics.





R51 105 13 275 R61 106 13 275 R71 1 114 400 R81 114 2 400 R911 117 400 R110 117 2 400 Ediff1 108 0 value {(v(104,103)*v(107))+(v(106,105)*(1-v(107)))} rdiff1 108 0 1K *Compensation Section ga1 0 134 108 0 1m rh1 134 0 5 Meg cc1 134 0 0.6 pF *Poles ep1 141 0 134 0 1.0 rpa1 141 142 200 cpa1 142 0 0.75 pF rpb1 142 143 200 cpb1 143 0 0.75 pF *Output Stage i011 15 150 1.0 mA i021 151 13 1.0 mA q71 13 143 150 qp q81 15 143 151 qn q91 15 150 152 qn q101 13 151 153 qp ros11 152 1 2 ros21 153 1 2 **************Amplifier #2********** q231 203 6 212 qp q241 204 214 213 qp q251 205 5 215 qp q261 206 217 216 qp la12 14 212 1 mA la22 14 213 1 mA lb12 14 215 1 mA lb22 14 216 1 mA Rga2 212 213 275 Rgb2 215 216 275 R231 203 13 275 R241 204 13 275 R251 205 13 275 R261 206 13 275 R271 8 214 400 R281 214 7 400 R291 8 217 400 R210 217 7 400 Ediff2 208 0 value {(v(204,203)*v(107))+(v(206,205)*(1-v(107)))} rdiff2 208 0 1K * Compensation Section ga2 0 234 208 0 1m

ga2 0 234 208 0 1n rh2 234 0 5 Meg cc2 234 0 0.6 pF



* Poles ep2 241 0 234 0 1.0 rpa2 241 242 200 cpa2 242 0 0.75 pF rpb2 242 243 200 cpb2 243 0 0.75 pF *Output Stage i0 12 15 250 1.0 mA i022 251 13 1.0 mA q271 13 243 250 qp q281 15 243 251 qn q291 15 250 252 qn q201 13 251 253 qp ros12 252 8 2 ros22 253 8 2 q331 303 12 312 qp q341 304 314 313 qp q351 305 11 315 qp q361 306 317 316 qp la13 14 312 1 mA la23 14 313 1 mA lb13 14 315 1 mA lb23 14 316 1 mA Rga3 312 313 275 Rgb3 315 316 275 R331 303 13 275 R341 304 13 275 R351 305 13 275 R361 306 13 275 R371 9 314 400 R381 314 10 400 R391 9 317 400 R310 317 10 400 Ediff3 308 0 value {(v(304,303)*(v(107))+(v(306,305)*(1-v(107)))} rdiff3 308 0 1K * Compensation ga3 0 334 308 01m rh3 334 0 5 Meg cc3 334 0 0.6 pF * Poles ep3 341 0 3340 1.0 rpa3 341 342 200 cpa3 342 0 0.75 pF rpb3 342 343 200 cpb3 343 0 0.75 pF * Output Stage i013 15 350 1.0 mA i023 351 13 1.0 mA q371 13 343 350 qp



q381 15 343 351 qn q391 15 350 352 qn q301 13 351 353 qp ros13 352 9 2 ros23 353 9 2

* Power Supply Current

ips 15 13 22 mA

*Models

.model qp pnp(is=1.5e-16 bf=300 tf=0.01 ns) .model qn npn(is=0.8e-18 bf=300 tf=0.01 ns) .ends

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FN7163 Rev 2.00 October 4, 2004

